



Modeling contamination migration on the Chandra X-ray Observatory — III

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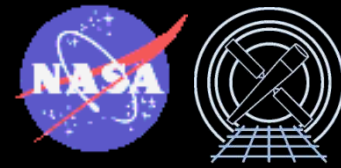
Outline



- Introduction
- Molecular contamination on ACIS filters
- Thermal model for ACIS cavity
- Molecular transport simulations
- Summary



Chandra's Advanced CCD Imaging Spectrometer (ACIS)



➤ ACIS cavity

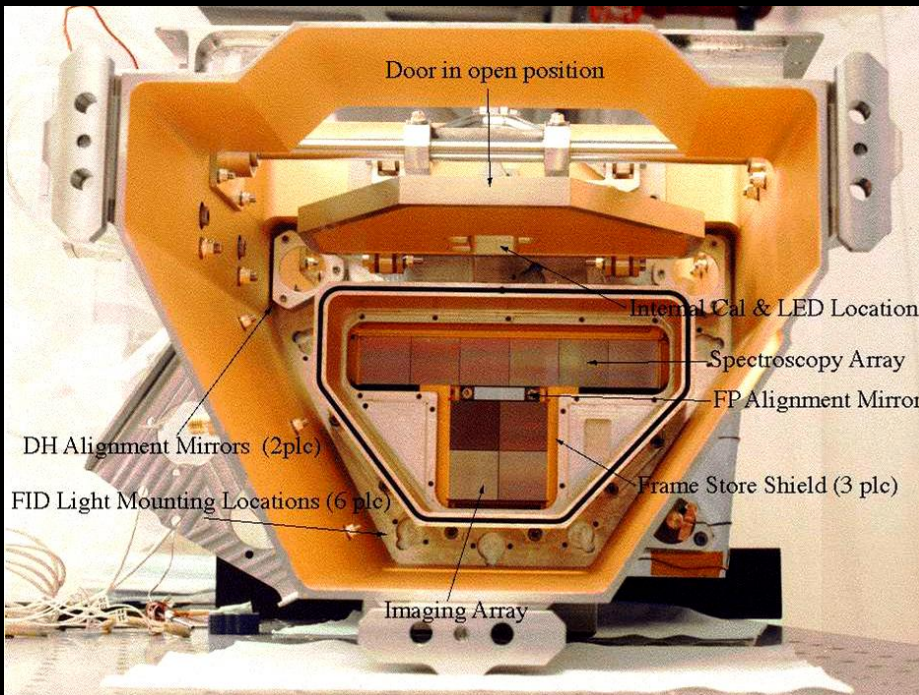
- ❑ Collimator
- ❑ Snoot & door
- ❑ Camera top & filters (OBF)

➤ ACIS operating temperatures

- ❑ Focal plane $T_{FP} = -120^{\circ}\text{C}$
- ❑ Camera housing $T_{DH} = -60^{\circ}\text{C}$
 - $\approx 8^{\circ}\text{C}$ colder with heaters off
- ❑ Optical blocking filters T_{OBF}
 - $\approx T_{DH} \approx -60^{\circ}\text{C}$ near OBF edge
 - $5\text{--}20^{\circ}\text{C}$ warmer near center depending on emissivity ϵ_{OBF}

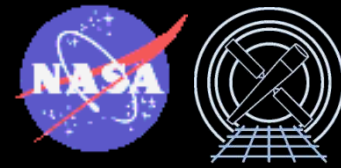
➤ Contamination on cold OBFs

- ❑ Mass column $\approx 200 \mu\text{g cm}^{-2}$.
 - $\leq 1 \text{ g}$ in entire *Chandra* optical cavity (calculated)
 - $\approx 30 \times$ pre-flight estimates
- ❑ Thicker near OBF edge



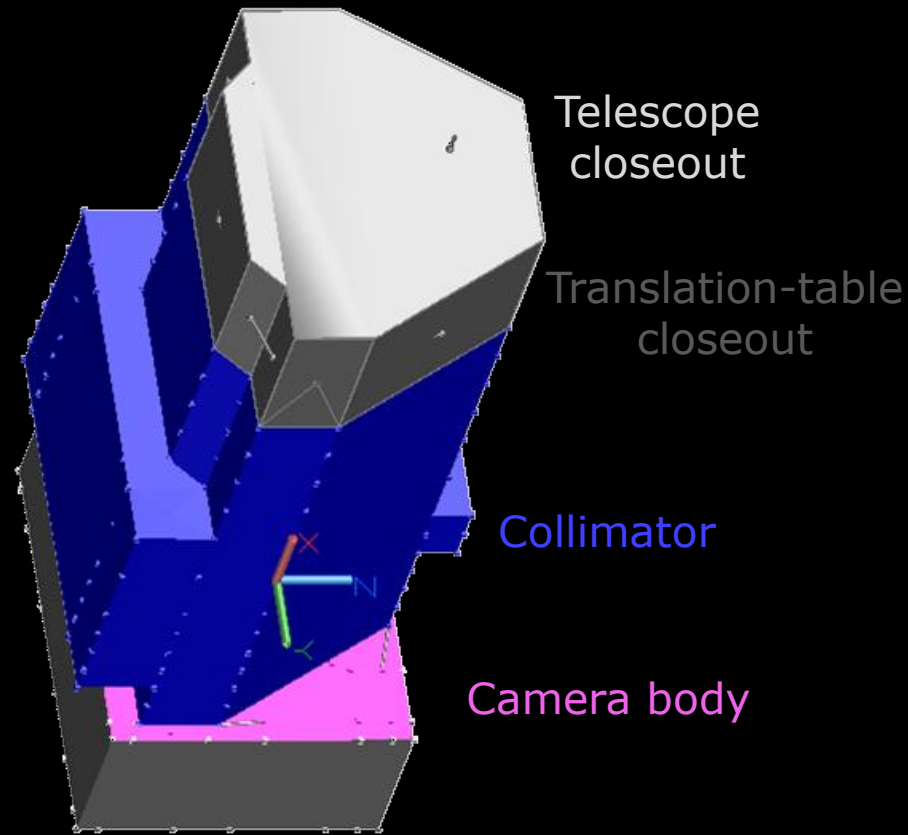


Contamination-migration simulations for Chandra



- 2004 (I)
 - ❑ Low-resolution geometrical model for ACIS cavity
 - ❑ Supported bake-out decision in 2004
- 2013 (II)
 - ❑ High-resolution geometrical model for ACIS cavity
 - ❑ Higher emissivity for contaminated surfaces
- 2015 (III)
 - ❑ Same model as 2013
 - ❑ Will support bake-out decision in 2016

- ACIS geometrical model (exterior view)





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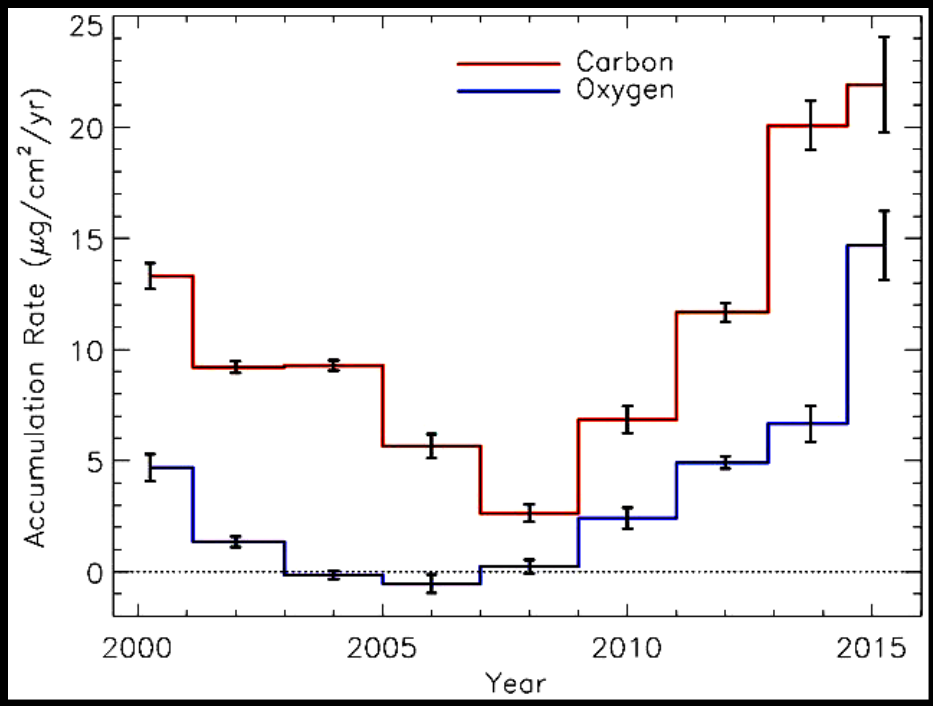
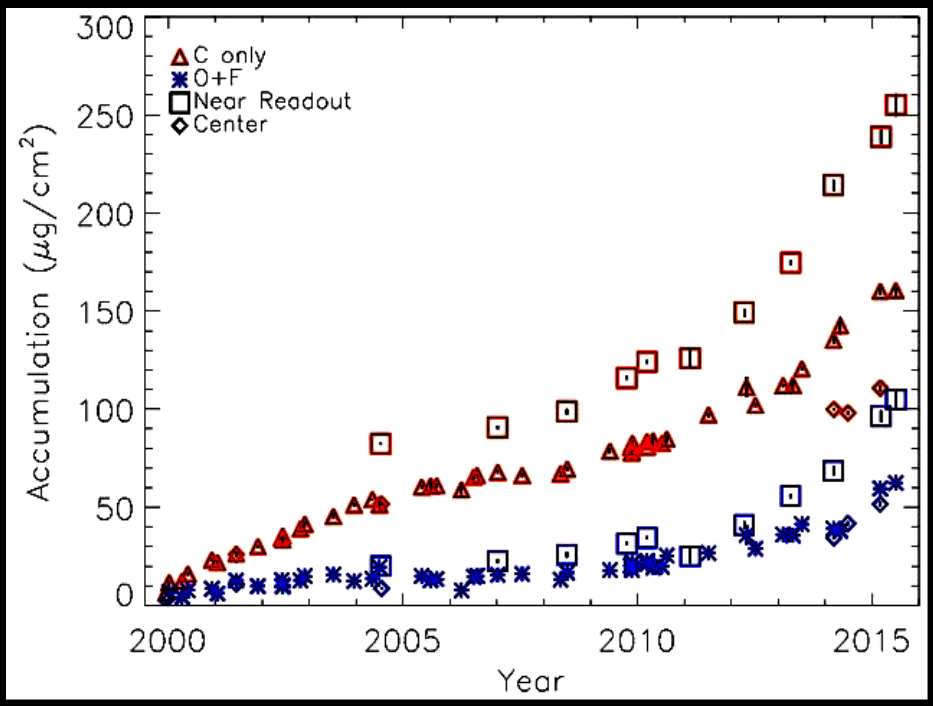


Evolution of mass column, its rate, and composition



- Accumulation of contaminants
 - LETG/ACIS-S spectra
 - Atomic (C,O,F) edge depths
 - Thickest near OBF edges

- Rate fell until about 2009 then started rising.
- Composition changes indicate multiple species.



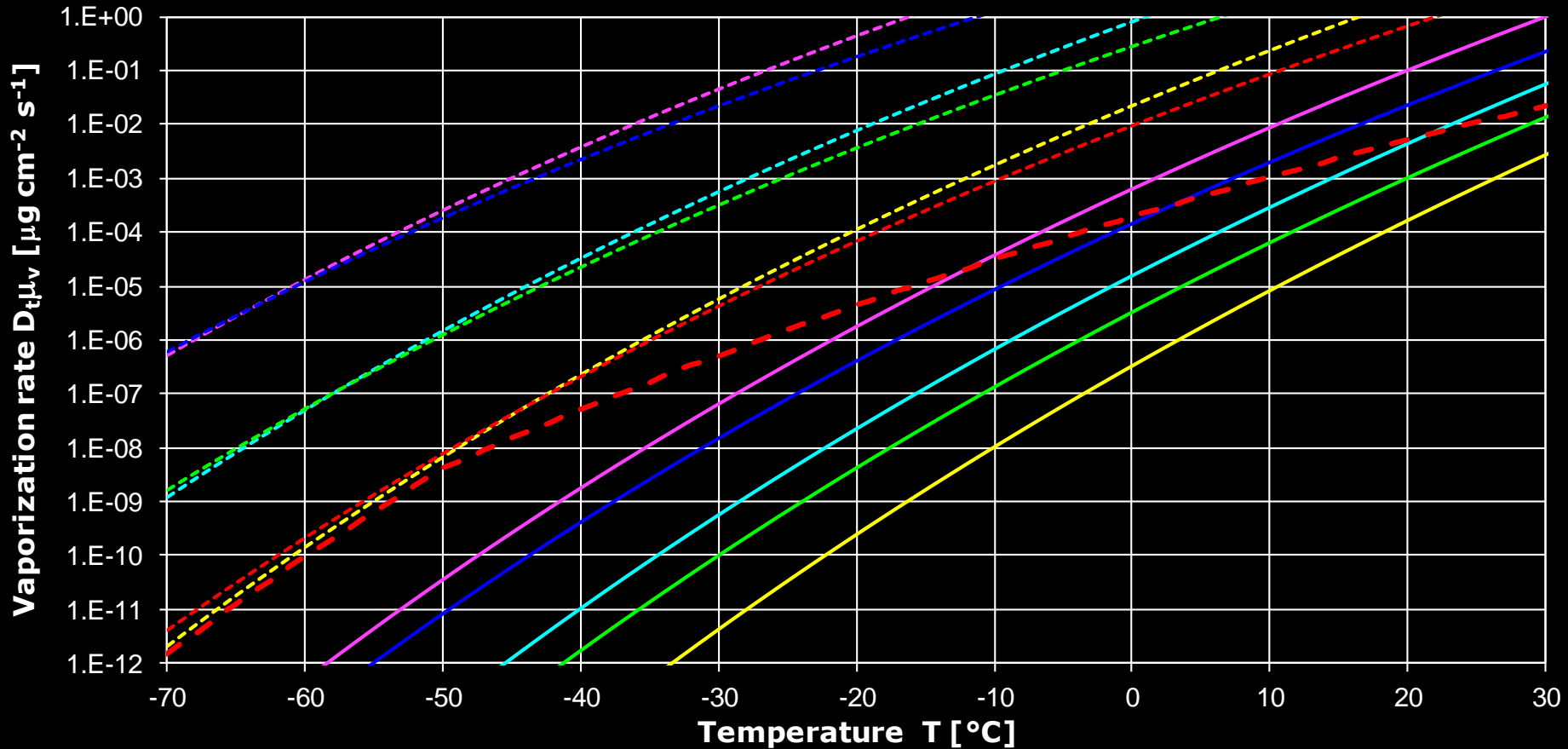


Temperature dependence of mass vaporization rate



Mass vaporization rates of some organic compounds

- tetradecane
- pentadecane
- hexadecane
- heptadecane
- octadecane
- nonadecane
- icosane
- heneicosane
- docosane
- tricosane
- tetracosane
- DOP

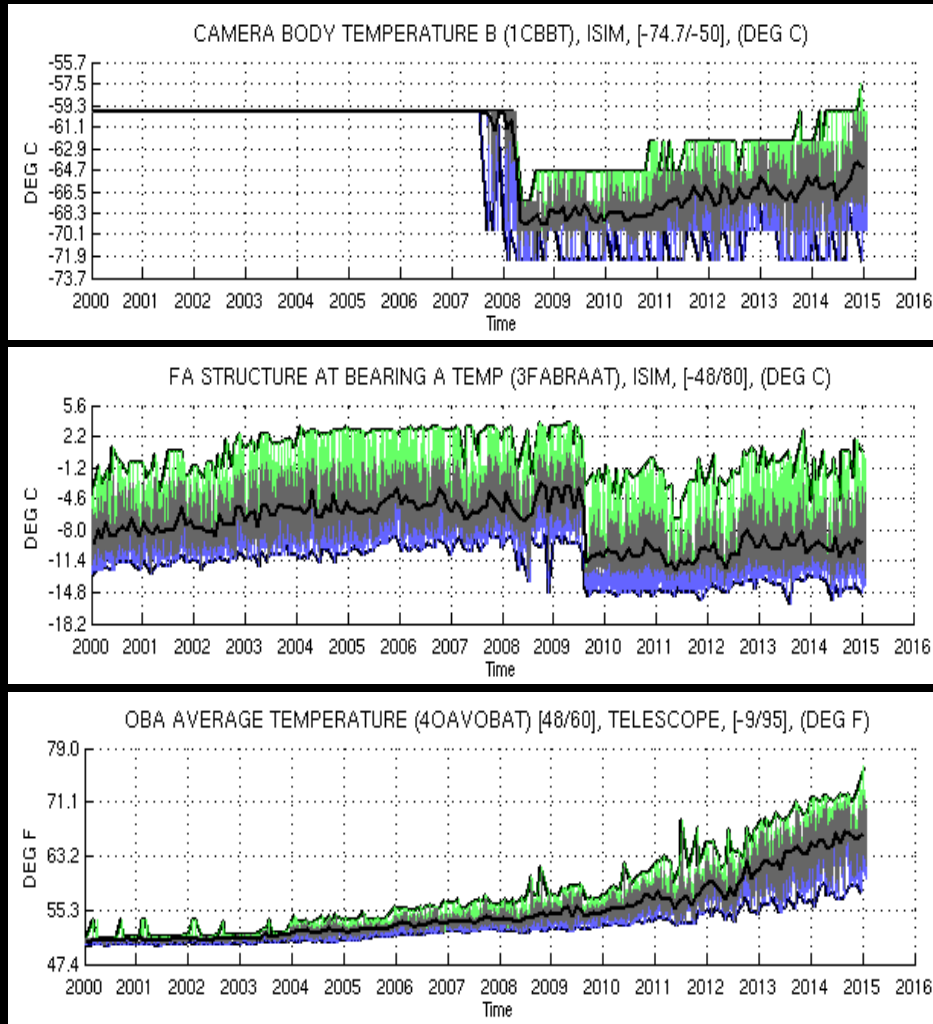




Thermal history



- Most systems are warming.
 - ❑ Continuing degradation of external insulation (MLI)
- Strive to keep ACIS focal plane cold to preserve performance.
 - ❑ Carefully plan observations.
 - ❑ Disabled some heaters.
 - ACIS detector-housing heater (2008 April)
 - A SIM focus-assembly heater (2009 August)
- Optical bench has warmed rapidly since about 2010.
 - ❑ New contamination source?





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ACIS geometric model (interior view)

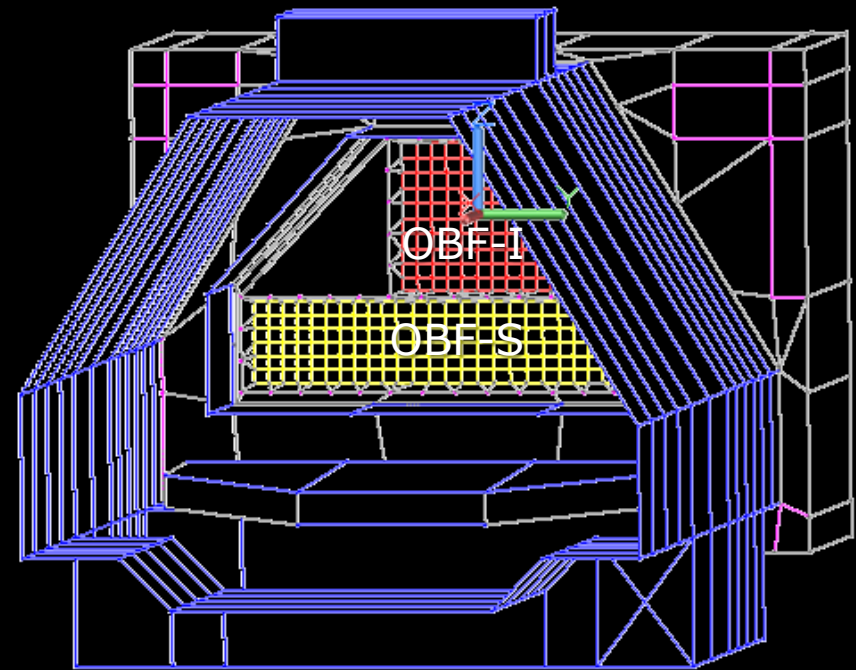
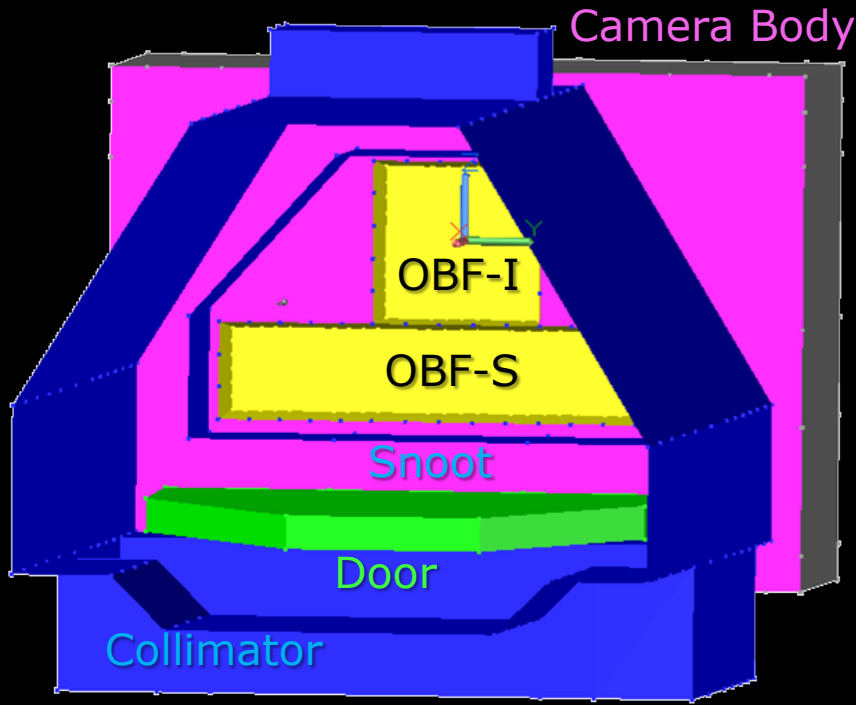


➤ Interior view of ACIS cavity

- ❑ Snoot & door inside collimator
- ❑ Camera top with OBFs

❑ High-resolution model maps temperature gradients

- OBF: 121 I & 203 S nodes
- Collimator: 12 axial zones



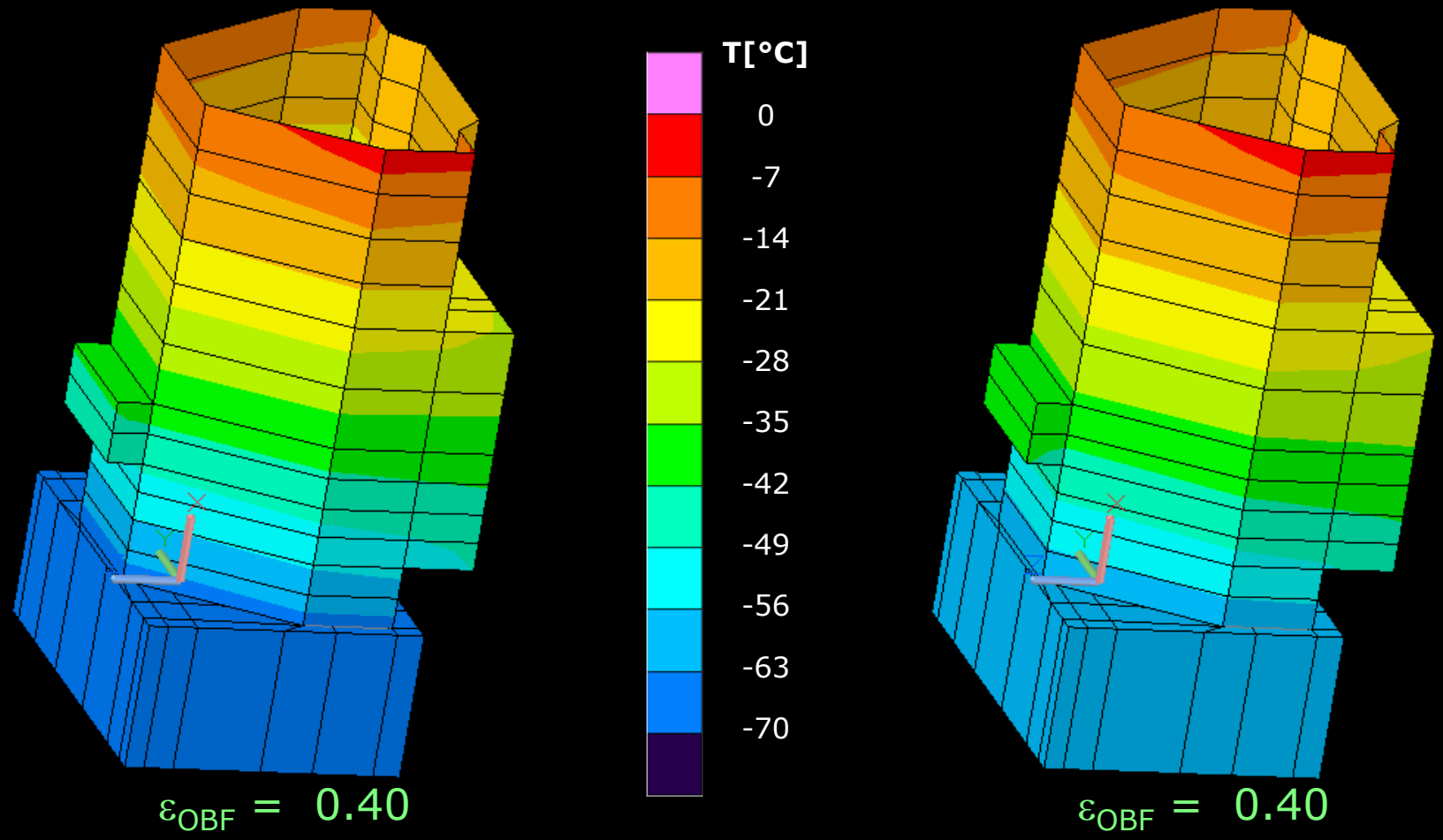


ACIS temperature distribution (operational conditions)



➤ DH heater OFF, $T_{FP} = -120^{\circ}\text{C}$

➤ $T_{DH} = -60^{\circ}\text{C}$, $T_{FP} = -120^{\circ}\text{C}$



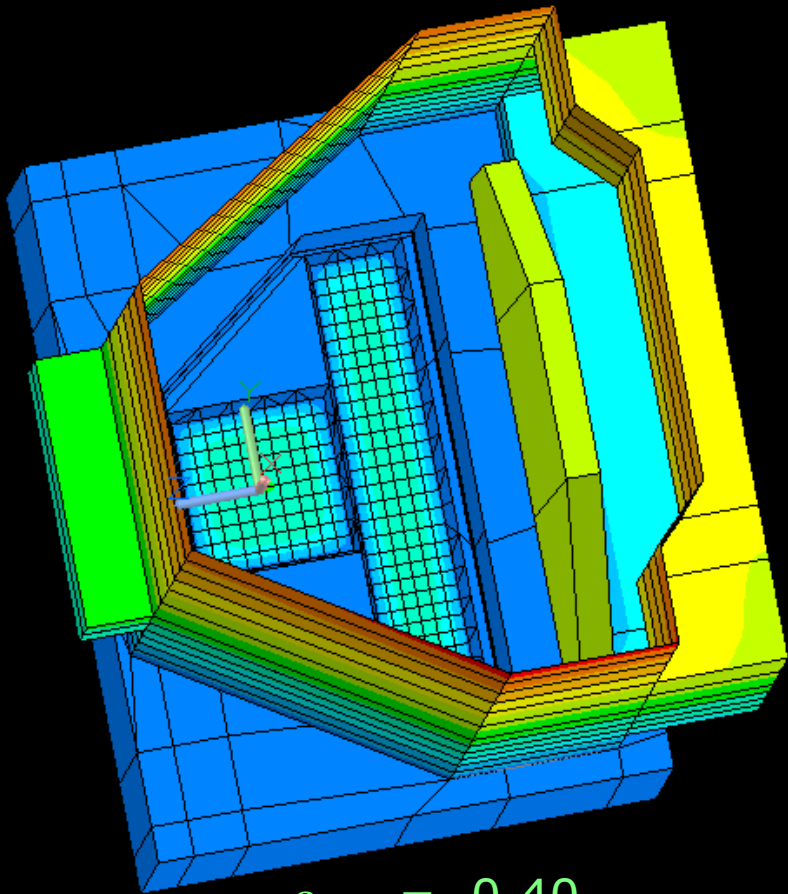


ACIS temperature distribution (operational conditions)

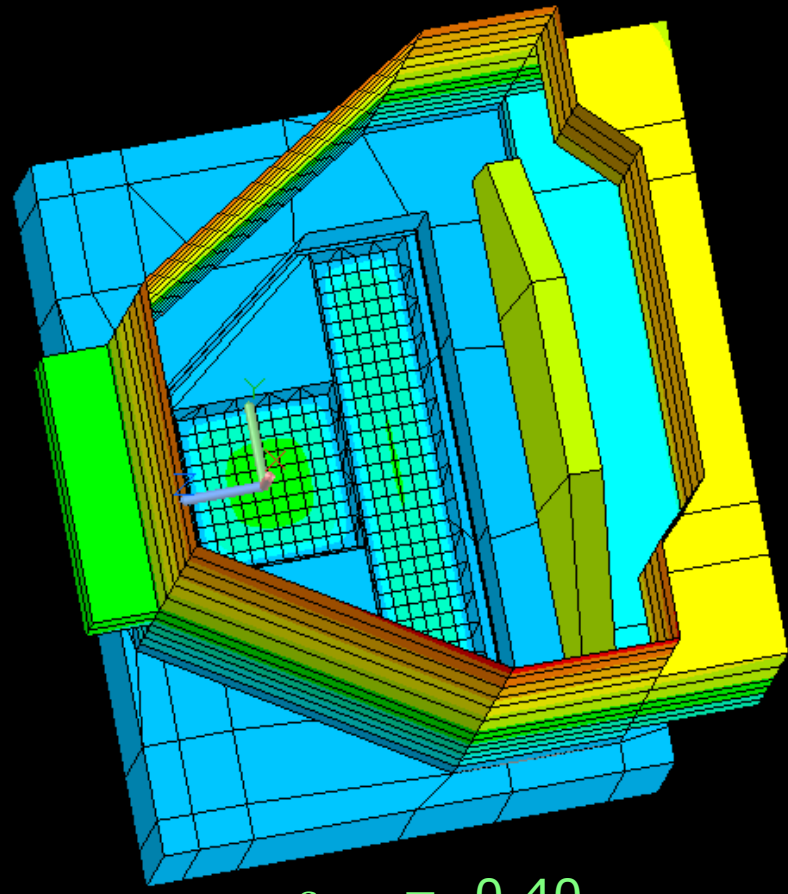
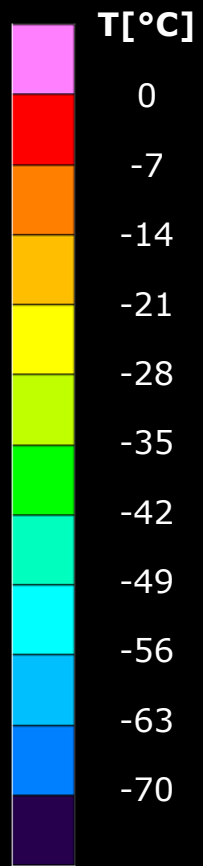


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$\epsilon_{\text{OBF}} = 0.40$



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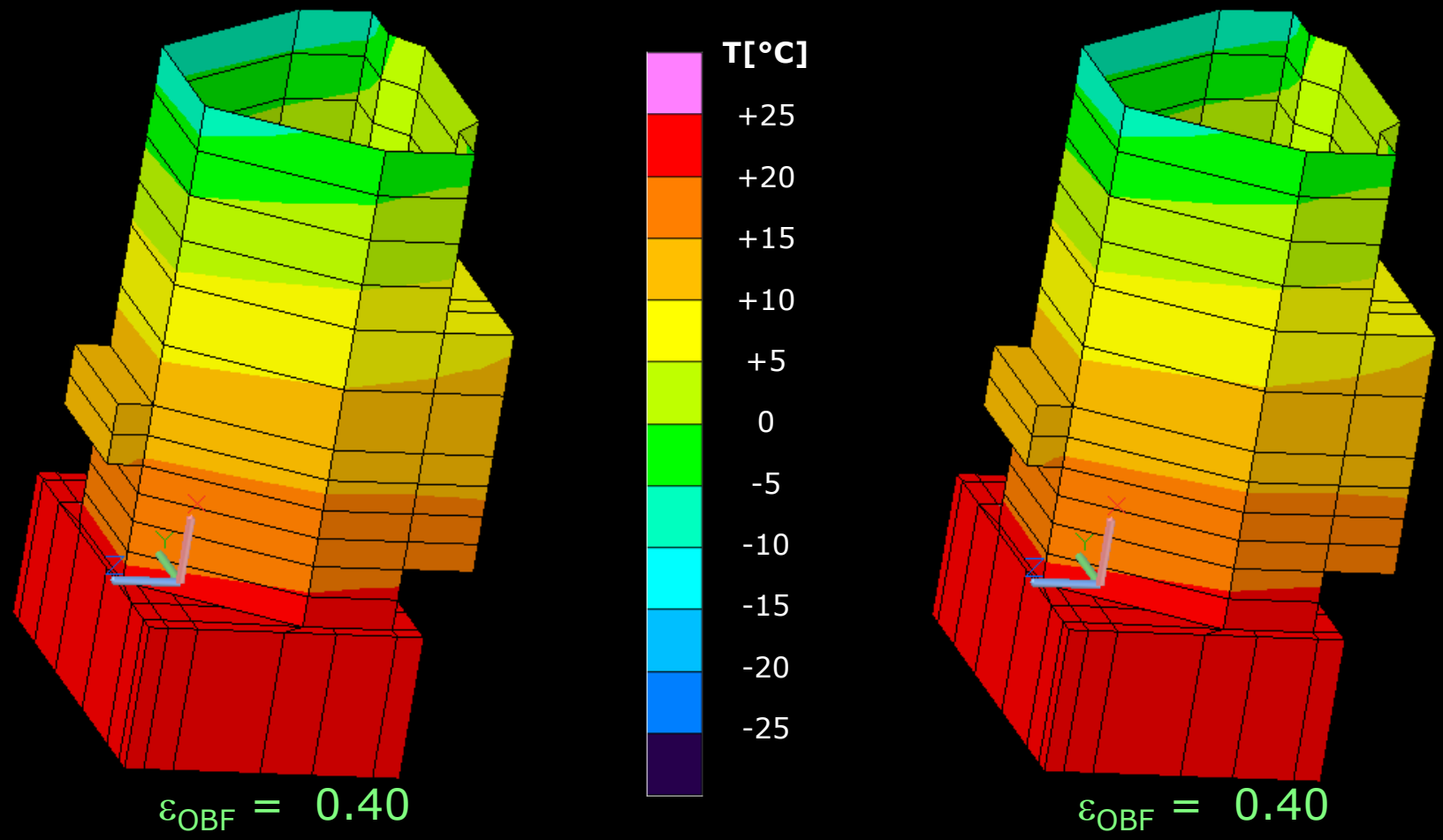


ACIS temperature distribution (bake-out conditions)



➤ $T_{DH} = +25^{\circ}\text{C}$, $T_{FP} = -60^{\circ}\text{C}$

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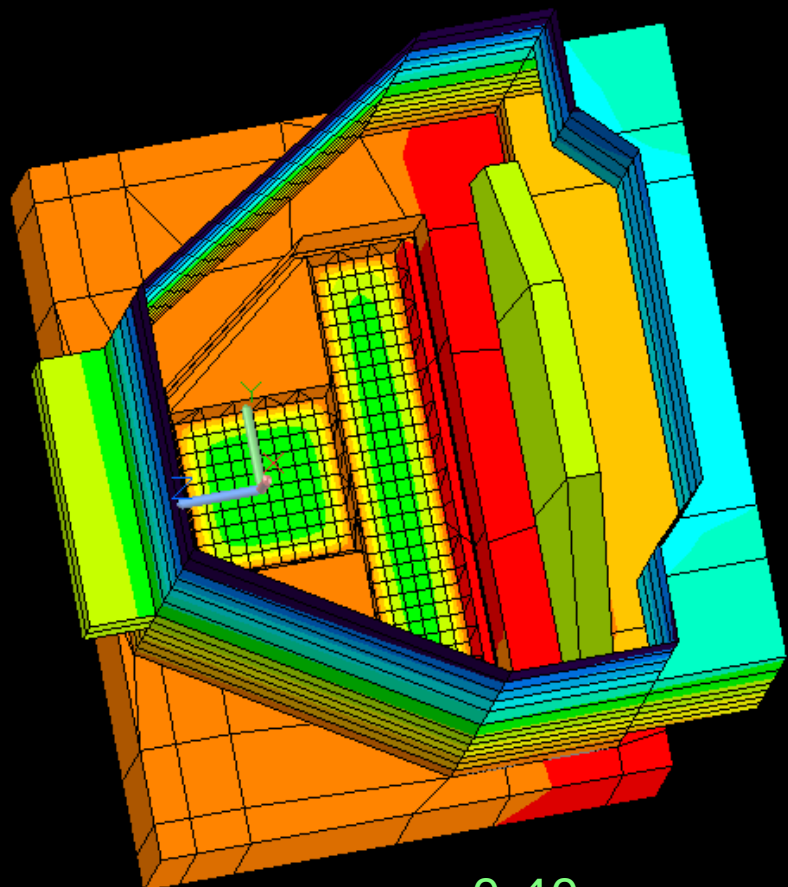


ACIS temperature distribution (bake-out conditions)

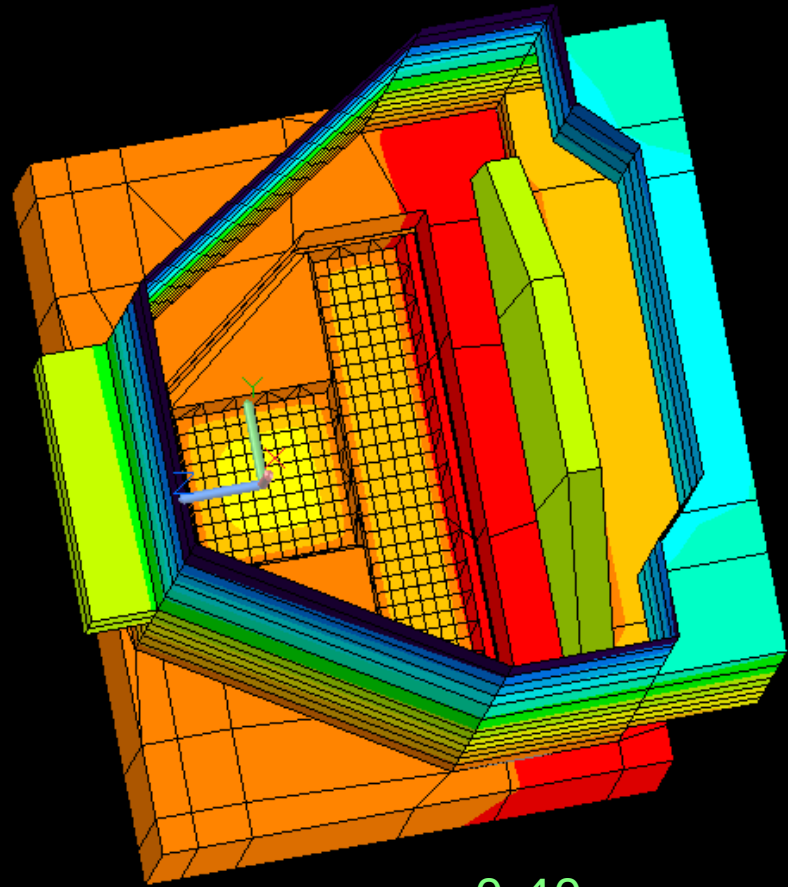
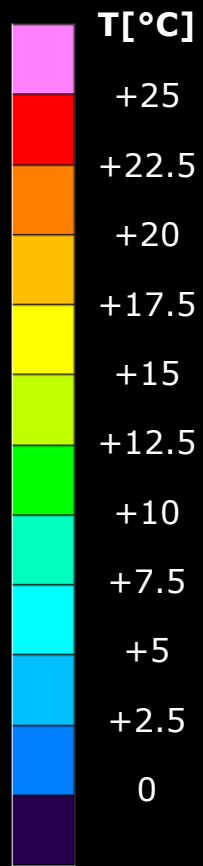


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Molecular flux equations and geometric view factors



➤ Net mass flux onto node j

$$\frac{d\mu_j}{dt} = -\dot{\mu}_v(T_j)\Theta(\mu_j) + \sum_k \dot{\mu}_v(T_k)\Theta(\mu_k) f_{jk} \frac{A_k}{A_j}$$

➤ Mass vaporization flux

□ Related to vapor pressure

$$\dot{\mu}_v(T) = \frac{P_v(T)}{\sqrt{2\pi RT/M}}$$

➤ Clausius–Clapeyron relation

□ Temperature dependence

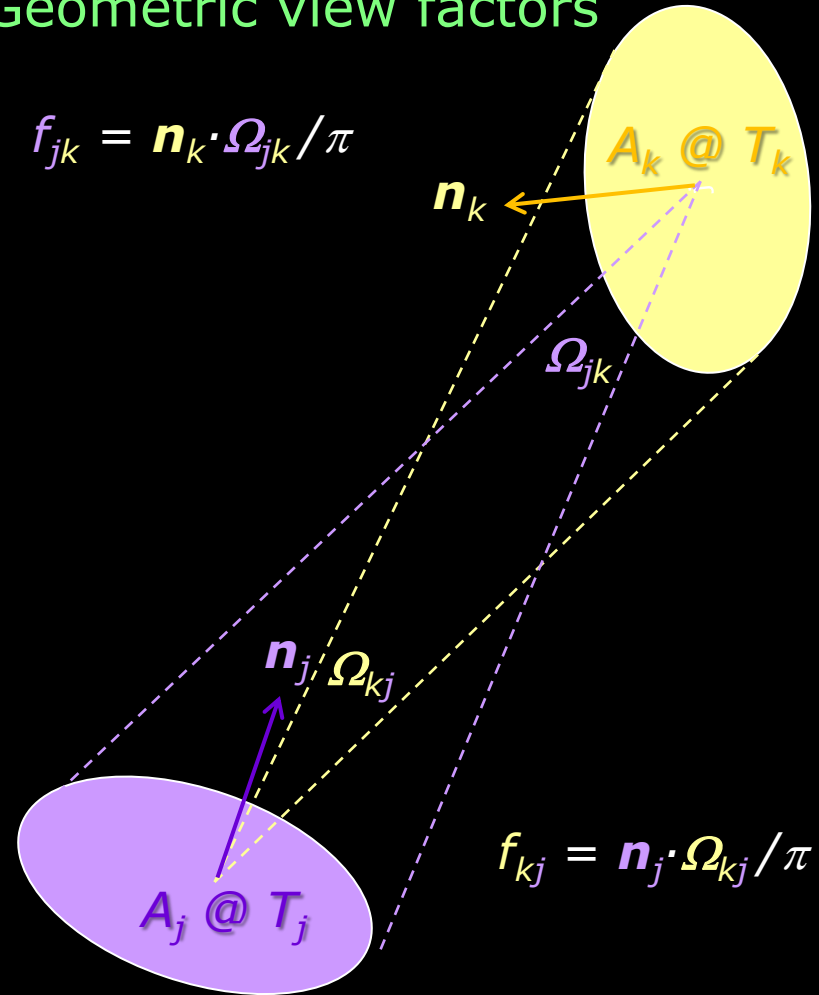
□ Vaporization enthalpy $\Delta_v H$

$$P_v(T) = P_v(T_o) \text{Exp} \left[-\frac{\Delta_v H}{R} \left(\frac{1}{T} - \frac{1}{T_o} \right) \right]$$

$$\dot{\mu}_v(T) = \dot{\mu}_v(T_o) \sqrt{\frac{T_o}{T}} \text{Exp} \left[-\frac{\Delta_v H}{R} \left(\frac{1}{T} - \frac{1}{T_o} \right) \right]$$

➤ Geometric view factors

$$f_{jk} = \mathbf{n}_k \cdot \boldsymbol{\Omega}_{jk} / \pi$$



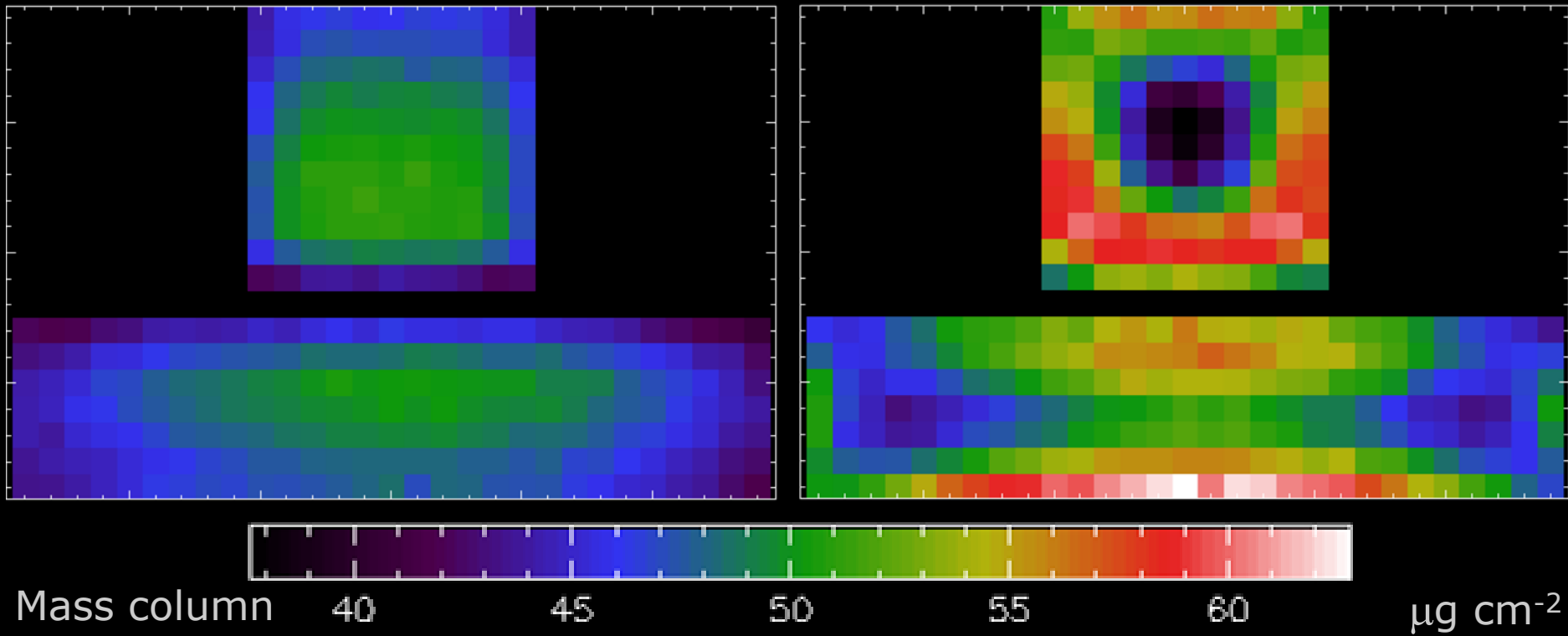


Simulations of contaminant accumulation onto ACIS OBFs



- Lower volatility contaminant
 - Deposition dominates.
 - Accumulates most at center.

- Higher volatility contaminant
 - Vaporization is significant.
 - Accumulates most at edges.





Accumulation simulation: two components

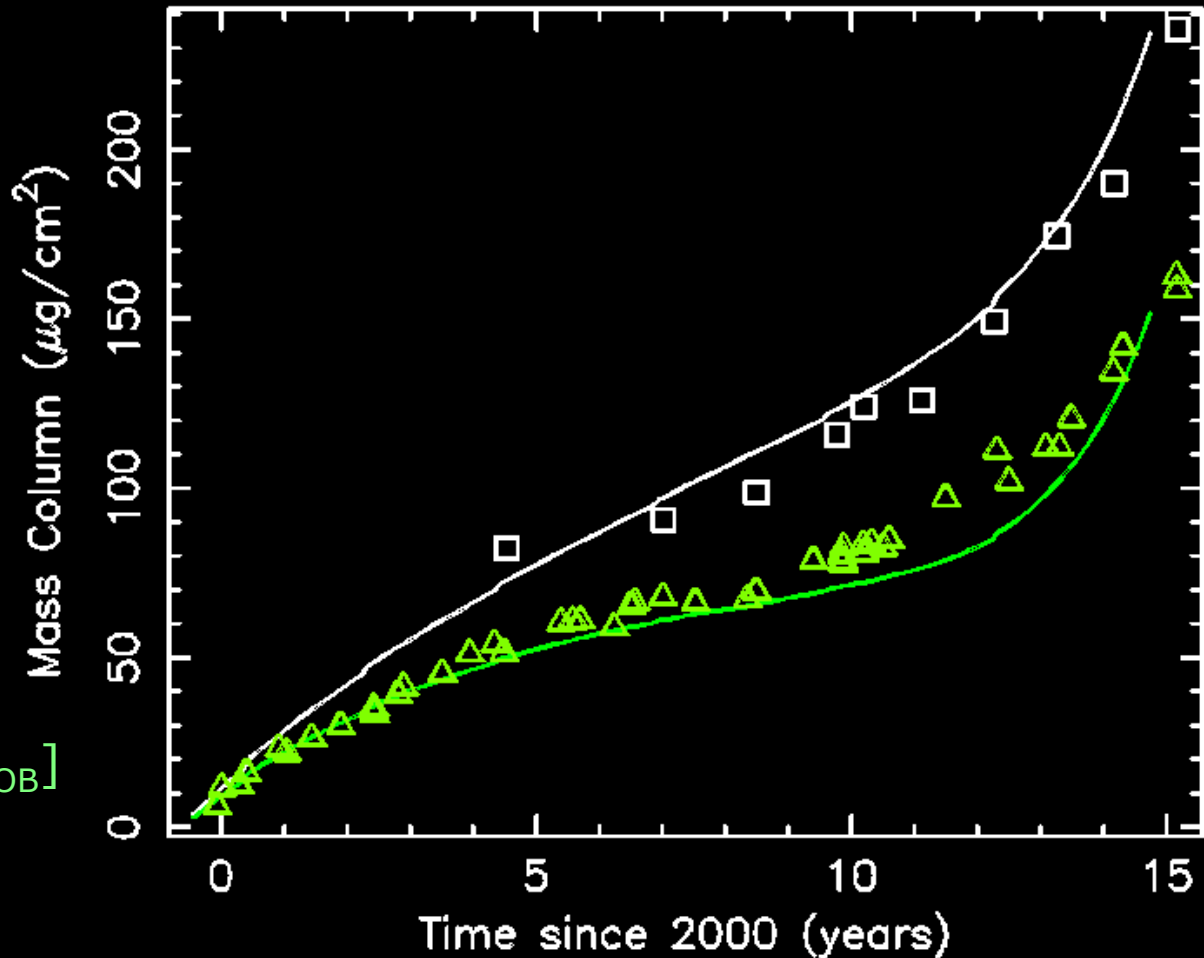


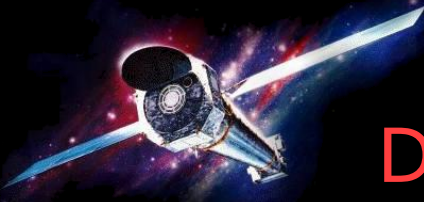
➤ Low-volatility component

- Source rate drops exponentially due to depletion.
 - 3.7-year timescale

➤ Medium-volatility component

- Source rate rises with increasing optical-bench T_{OB} .
 - $\propto \text{Exp}[-\text{constant}/T_{OB}]$
 - Rises until source depletion occurs.

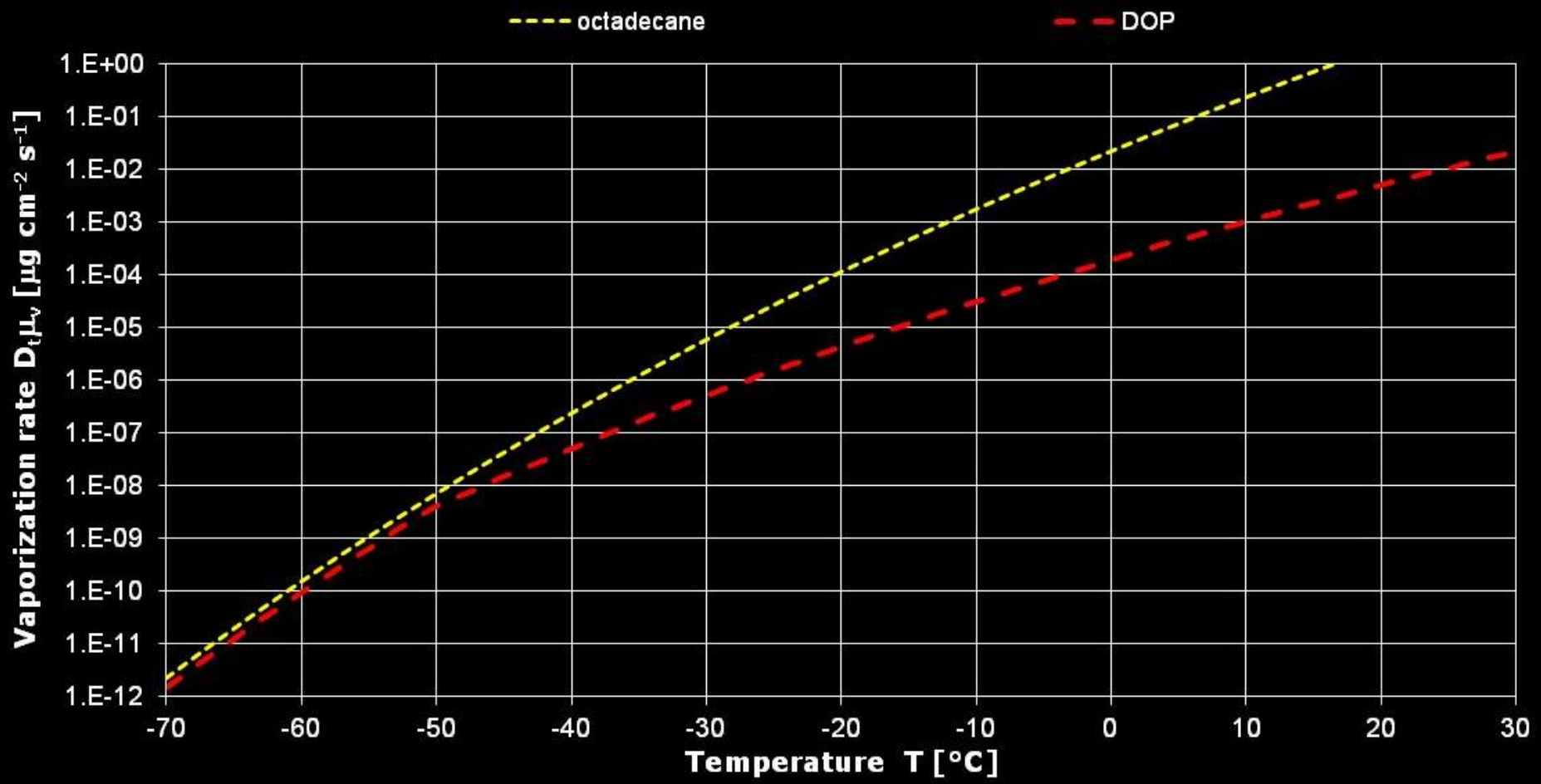




Vaporization rate: Dependence upon phase state

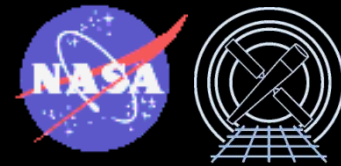


Mass vaporization rates of a solid and of a liquid





Bake-out simulation: Octadecane mass



➤ Warm focal plane

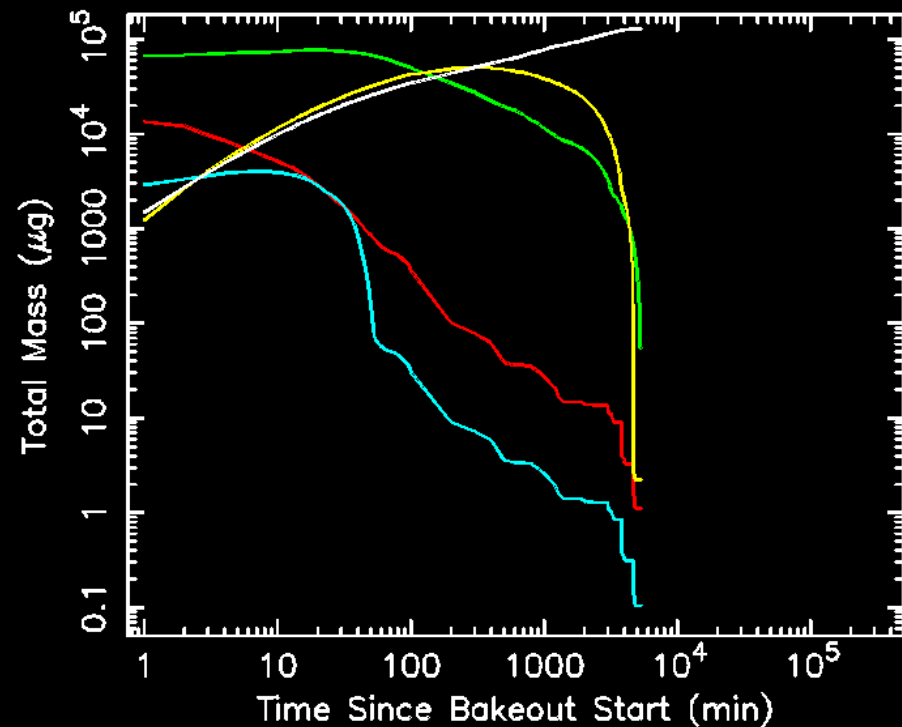
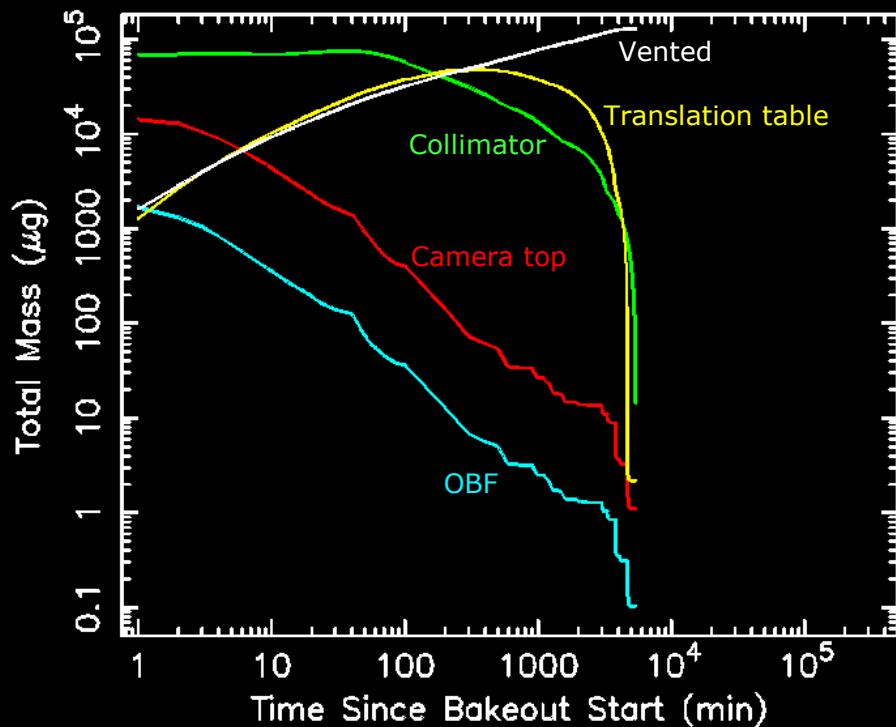
□ $T_{DH} = +25^{\circ}\text{C}$

□ $T_{FP} = +25^{\circ}\text{C}$

➤ Cool focal plane

□ $T_{DH} = +25^{\circ}\text{C}$

□ $T_{FP} = -60^{\circ}\text{C}$





Bake-out simulation: Octadecane column



➤ Warm focal plane

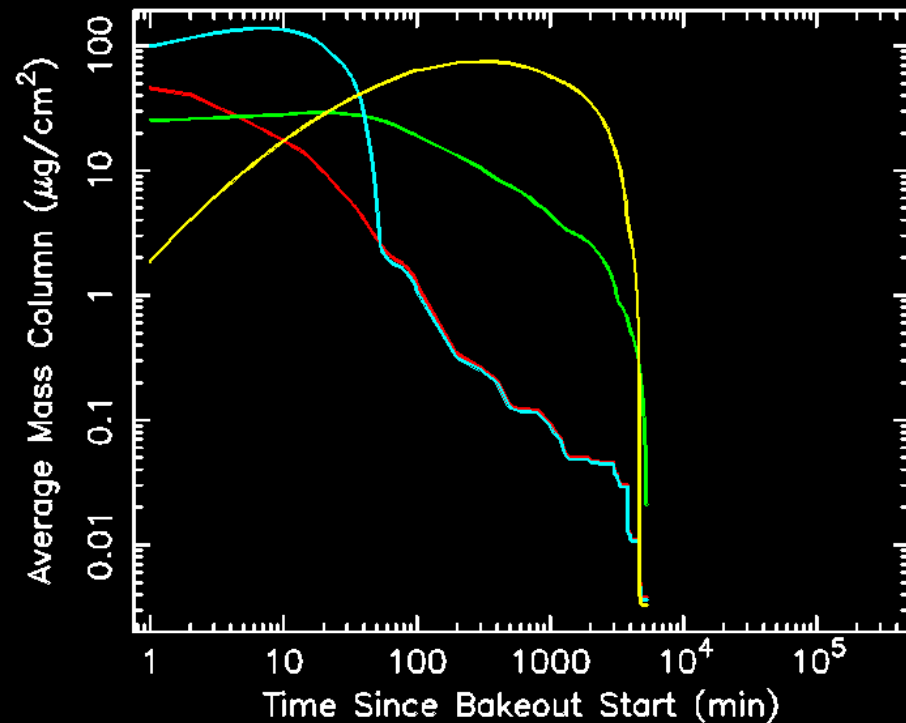
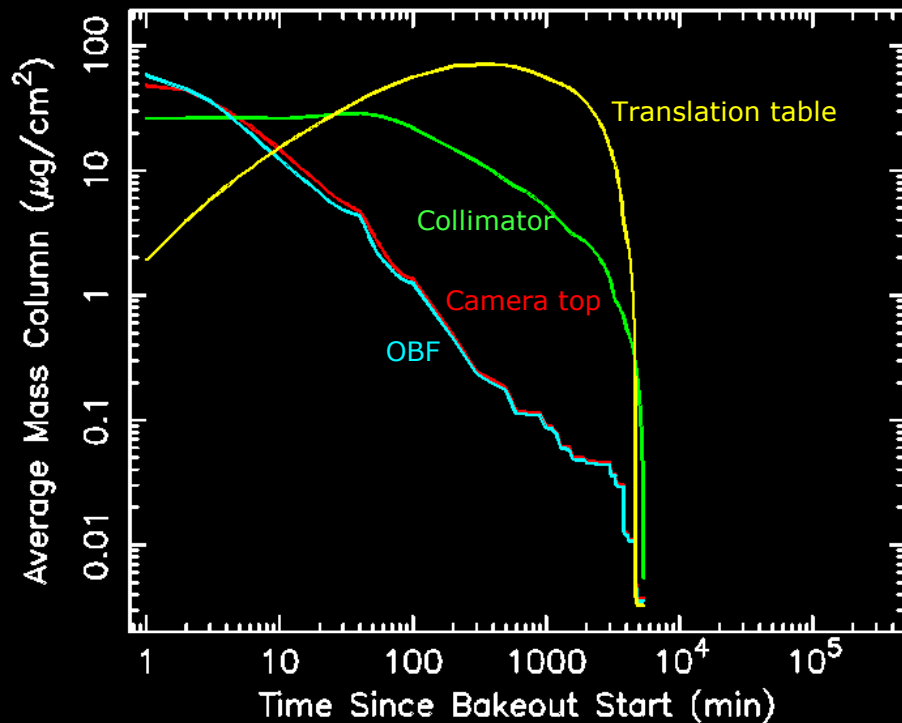
□ $T_{DH} = +25^{\circ}\text{C}$

□ $T_{FP} = +25^{\circ}\text{C}$

➤ Cool focal plane

□ $T_{DH} = +25^{\circ}\text{C}$

□ $T_{FP} = -60^{\circ}\text{C}$





Bake-out simulation: Dioctyl phthalate mass



➤ Warm focal plane

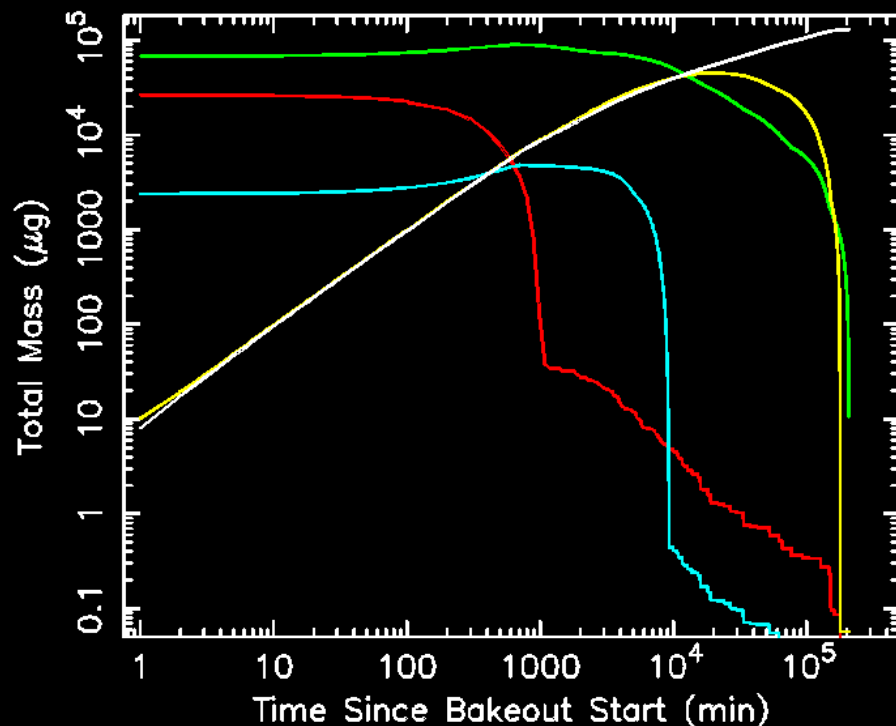
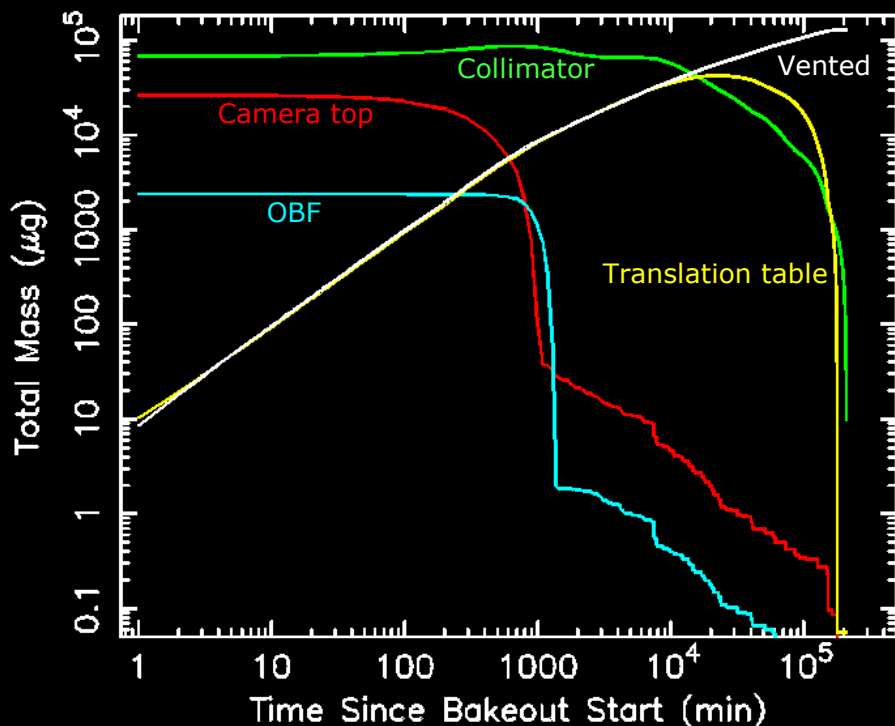
□ $T_{DH} = +25^{\circ}\text{C}$

□ $T_{FP} = +25^{\circ}\text{C}$

➤ Cool focal plane

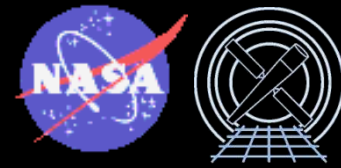
□ $T_{DH} = +25^{\circ}\text{C}$

□ $T_{FP} = -60^{\circ}\text{C}$





Bake-out simulation: Dioctyl phthalate column



➤ Warm focal plane

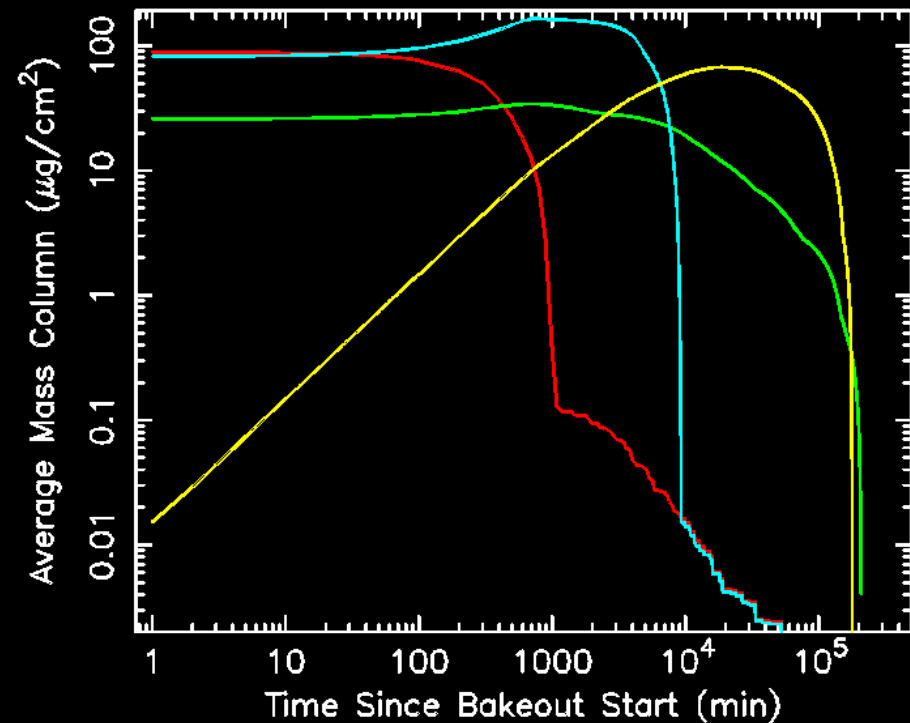
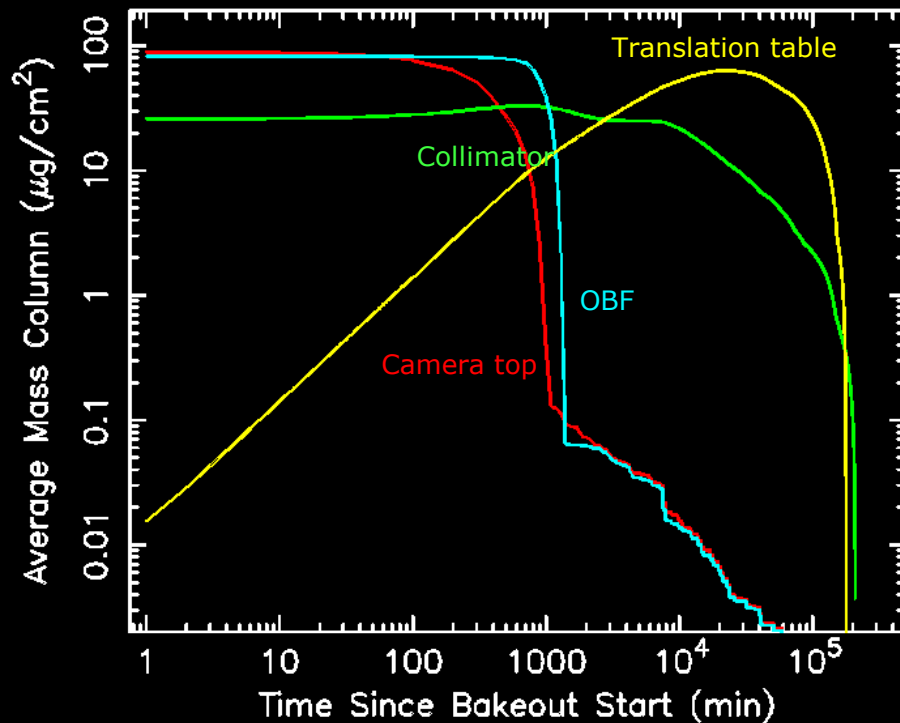
□ $T_{DH} = +25^{\circ}\text{C}$

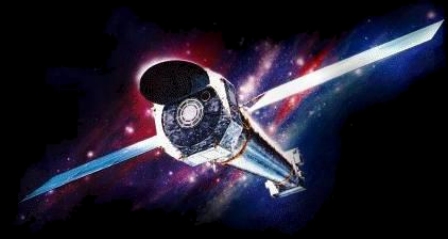
□ $T_{FP} = +25^{\circ}\text{C}$

➤ Cool focal plane

□ $T_{DH} = +25^{\circ}\text{C}$

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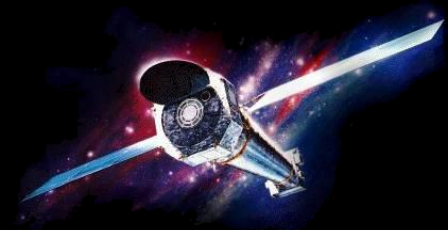




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Summary



- Contamination-migration simulation provides a useful tool.
 - Utility for absolute predictions is still limited.
 - Absolute predictions require knowledge of contaminant's volatility.
 - Uncertainty in temperatures propagates exponentially to rate error.
 - Model may require additional physics.
 - Treatment of multiple molecular species
 - Dependence of thermal emissivity upon contaminant mass column
 - Affects temperature distribution and thus mass vaporization rate
 - Surface redistribution, especially for a liquid contaminant
- Will use model to provide input for a bake-out decision.
 - Constrain properties of molecular contaminant(s).
 - Simulate contamination migration under potential scenarios.
 - Turning housing heaters back ON
 - Various bake-out conditions for ACIS